

RF CHARACTERISTICS

Frequency range : **0 - 18 GHz**
Impedance : **50 Ohms**

Frequency (GHz)	DC - 3	3 - 8	8 - 12.4	12.4 - 18
VSWR max	1.20	1.30	1.40	1.50
Insertion loss max	0.20 dB	0.30 dB	0.40 dB	0.50 dB
Isolation min	80 dB	70 dB	65 dB	60 dB
Average power (*)	240 W	150 W	120 W	100 W

Passive intermodulation	
Tone 1	1810 MHz, approximately 43 dBm
Tone 2	1850 MHz, approximately 43 dBm
3 rd order PIM	- 160 dBc at 1770 MHz

Depending on application, carrier powers and frequencies, PIM measurements can vary.
PIM testing is not measured during product acceptance test.

ELECTRICAL CHARACTERISTICS

Actuator : **LATCHING**
Nominal current ** : **320 mA**
Actuator voltage (Vcc) : **12V (10.2 to 13V)**
Terminals : **solder pins (250°C max. / 30 sec.)**
TTL inputs (E) - High level : **2.2 to 5.5 V / 800µA at 5.5 V**
- Low level : **0 to 0.8 V / 20µA at 0.8 V**

MECHANICAL CHARACTERISTICS

Connectors***** : **SMA female per MIL-C 39012**
Life : **2 million cycles**
Switching Time*** : **< 15 ms**
Construction : **Splashproof**
Weight : **< 100 g**

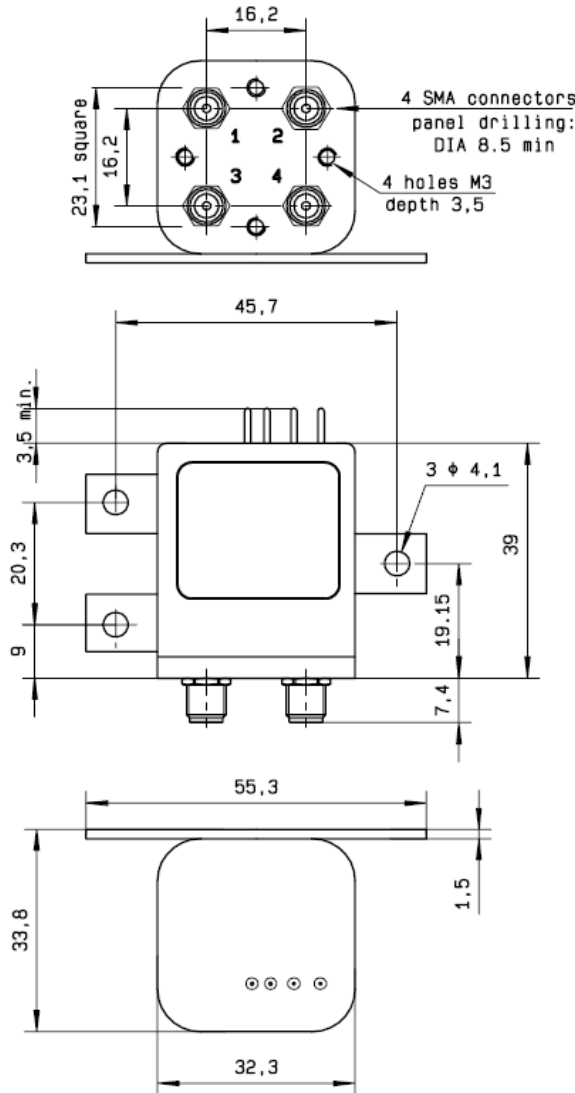
ENVIRONMENTAL CHARACTERISTICS

Operating temperature range : **-25°C to +70°C**
Storage temperature range : **-55°C to +85°C**

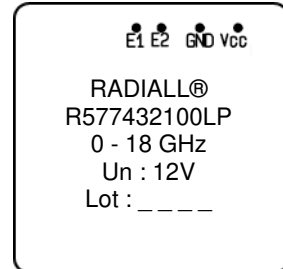
- (* Average power at 25°C per RF Path)
(** At 25° C ±10%)
(*** Nominal voltage ; 25° C)
(***** Recommended mating torque: 80-120 N.cm)



DRAWING

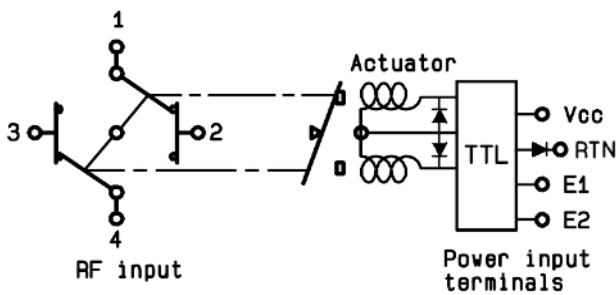


LABEL



General tolerances : ±0.5 mm

SCHEMATIC DIAGRAM



TTL input	RF Continuity
E1=1 / E2=0	1 ↔ 3 / 2 ↔ 4
E1=0 / E2=1	1 ↔ 2 / 3 ↔ 4
E1=0 / E2=0	Memory
E1=1 / E2=1	Forbidden